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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/939,330	08/24/2001	Alfred Kersch	L&L-10078	3872
24131	7590 05/19/2004		EXAMINER	
LERNER AND GREENBERG, PA			FULLER, ERIC B	
P O BOX 2480 HOLLYWOOD, FL 33022-2480			ART UNIT	PAPER NUMBER
	_,		1762	

DATE MAILED: 05/19/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

THE STATE OF THE S	A 12 42 N -		
	Application No.	Applicant(s)	
	09/939,330	KERSCH ET AL.	
Office Action Summary	Examiner	Art Unit	
	Eric B Fuller	1762	
The MAILING DATE of this communication ap Period for Reply	pears on the cover sheet w	rith the correspondence address	
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1. after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a replection of the period for reply is specified above, the maximum statutory period Failure to reply within the set or extended period for reply will, by stature Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	.136(a). In no event, however, may a oly within the statutory minimum of thi I will apply and will expire SIX (6) MO te, cause the application to become A	reply be timely filed rty (30) days will be considered timely. NTHS from the mailing date of this communicati BANDONED (35 U.S.C. § 133).	ion.
Status			
1) Responsive to communication(s) filed on 151	<u> March 2004</u> .		
2a)⊠ This action is FINAL . 2b)□ Thi	s action is non-final.		
3) Since this application is in condition for allowa	ance except for formal mat	ters, prosecution as to the merits	is
closed in accordance with the practice under	Ex parte Quayle, 1935 C.I	D. 11, 453 O.G. 213.	
Disposition of Claims			
4) Claim(s) <u>1-9</u> is/are pending in the application.			
4a) Of the above claim(s) is/are withdra	awn from consideration.		
5) Claim(s) is/are allowed.			
6)⊠ Claim(s) <u>1-9</u> is/are rejected.			
7) Claim(s) is/are objected to.			
8) Claim(s) are subject to restriction and/	or election requirement.		
Application Papers			
9) The specification is objected to by the Examin	er.		
10) The drawing(s) filed on is/are: a) ac	cepted or b) Objected to	by the Examiner.	
Applicant may not request that any objection to the	e drawing(s) be held in abeya	nce. See 37 CFR 1.85(a).	
Replacement drawing sheet(s) including the correct		•	(d).
11) ☐ The oath or declaration is objected to by the E	xaminer. Note the attache	d Office Action or form PTO-152.	
Priority under 35 U.S.C. § 119			
12)⊠ Acknowledgment is made of a claim for foreign a)⊠ All b)□ Some * c)□ None of:	n priority under 35 U.S.C.	§ 119(a)-(d) or (f).	
1. Certified copies of the priority documen	ts have been received.		
2. Certified copies of the priority documen	ts have been received in A	Application No	
3. Copies of the certified copies of the price	ority documents have beer	received in this National Stage	
application from the International Burea	, , , , , , , , , , , , , , , , , , , ,		
* See the attached detailed Office action for a lis	t of the certified copies not	received.	
Attachment(s)	_		
Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO-948)		Summary (PTO-413) s)/Mail Date	
 2) ☐ Notice of Draftsperson's Patent Drawing Review (P10-948) 3) ☐ Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08 Paper No(s)/Mail Date 2. 		nformal Patent Application (PTO-152)	
S. Patent and Trademark Office			

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DETAILED ACTION

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1-3 and 5-9 are rejected under 35 U.S.C. 103(a) as being unpatentable over Vaartstra (US 6,159,855) in view of Wang et al. (US 5,871,811) in further view of Tanaka et al. (US 6,039,834).

Vaartstra teaches a process of forming ferroelectric or perovskite films by chemical vapor deposition (column 7, lines 45-55). Water vapor may be used as a reactant gas (column 11, lines 5-10), which reads on applicant's "auxiliary gas". Water has a dipole moment and, according to the applicant's specification on page 10, lines 15-20, has the property required by claim 1. The water vapor is fed by an external supply source that is a storage container (figure 1, ref. 19). The carrier gases, precursor gases, and water vapor are all fed into the reaction chamber through a showerhead (column 12, lines 20-26). The substrate is mounted opposite the showerhead and a pump is used to exhaust the reaction chamber (figure 1, ref. 42, 46). The reference is silent in teaching the distance between the showerhead and the substrate. However, Wang teaches that by having the distance between the

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showerhead and the substrate be less than one centimeter, the reactants are confined to the area between the substrate and the showerhead, which results in increased reaction efficiency, increased rate of reaction, and prevents deposition everywhere except on the wafer. It would have been obvious at the time the invention was made to a person having ordinary skill in the art to use a distance of less than one centimeter for the separation between the showerhead and the substrate in the process taught by Vaartstra. By doing so, one would reap the benefits of increased reaction efficiency, increased rate of reaction, and preventing deposition everywhere except on the wafer.

The references, collectively, fail to explicitly teach providing a connecting line directly connecting the further gas outlet opening to one of the inlet openings, with a valve in the connecting line for controlling gas flow. However, Tanaka teaches an upgrade for CVD systems (abstract) that has such a configuration (column 15, lines 25-51). The benefit of using such a configuration is so that the CVD apparatus may be self-cleaning by recirculating radicals. It would have been obvious at the time the invention was made to a person having ordinary skill in the art to use the upgrade taught by Tanaka, and the corresponding configuration, in the process taught by Vaartstra in view of Wang. By doing so, the apparatus may be made self-cleaning.

Claim 4 is rejected under 35 U.S.C. 103(a) as being unpatentable over Vaartstra (US 6,159,855) in view of Wang et al. (US 5,871,811) in further view of Tanaka et al. (US 6,039,834), as applied to claim 1 above, and further in view of Arvidson (US 5,118,485).

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Vaartstra, in view of Wang and Tanaka, teaches the limitations of claim 1, as shown above, but fails to teach using a recycle stream with a pump to circulate auxiliary gas from the exit of the chamber to the inlet. However, Arvidson teaches that it is well known to recover unused reactant that has passed through a CVD process and recycle it back to the inlet streams so that there is less waste (column 2, lines 44-68). Therefore, it would have been obvious at the time the invention was made to a person having ordinary skill in the art to recycle elements of the exhaust in the process taught by Vaartstra, in view of Wang and Tanaka, with the expectation of achieving less waste.

Response to Arguments

Applicant argues that Tanaka teaches that different reactor chambers are connected, thus fails to teach connecting the inlet and outlet openings of one and the same reactor. This is not found convincing. Tanaka teaches in column 15, lines 25-51, that a connection line connects the outlet and inlet of processing chamber (400) of figure 3(b). As there is only one processing chamber in figure 3(b), this is a teaching of connecting the inlet and outlet openings of one and the same reactor.

Conclusion

THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within

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TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Eric B Fuller whose telephone number is (571) 272-1420. The examiner can normally be reached on Mondays through Thursdays.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Shrive P Beck, can be reached on (571) 272-1415. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

EBF

TIMOTHY MEEKS